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#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

2014110	
Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I <sup>2</sup> C, IrDA, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	50
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	1.85V ~ 3.8V
Data Converters	A/D 8x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32gg942f512-qfp64t

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

# **1 Ordering Information**

Table 1.1 (p. 2) shows the available EFM32GG942 devices.

#### Table 1.1. Ordering Information

Ordering Code	Flash (kB)	RAM (kB)	Max Speed (MHz)	Supply Voltage (V)	Temperature (ºC)	Package
EFM32GG942F512G-E-QFP64	512	128	48	1.98 - 3.8	-40 - 85	TQFP64
EFM32GG942F1024G-E-QFP64	1024	128	48	1.98 - 3.8	-40 - 85	TQFP64

Adding the suffix 'R' to the part number (e.g. EFM32GG942F512G-E-QFP64R) denotes tape and reel.

Visit www.silabs.com for information on global distributors and representatives.

Descriptor-Based Scatter/Gather DMA and supports up to 6 OUT endpoints and 6 IN endpoints, in addition to endpoint 0. The on-chip PHY includes all OTG features, except for the voltage booster for supplying 5V to VBUS when operating as host.

## 2.1.11 Inter-Integrated Circuit Interface (I2C)

The I<sup>2</sup>C module provides an interface between the MCU and a serial I<sup>2</sup>C-bus. It is capable of acting as both a master and a slave, and supports multi-master buses. Both standard-mode, fast-mode and fast-mode plus speeds are supported, allowing transmission rates all the way from 10 kbit/s up to 1 Mbit/s. Slave arbitration and timeouts are also provided to allow implementation of an SMBus compliant system. The interface provided to software by the I<sup>2</sup>C module, allows both fine-grained control of the transmission process and close to automatic transfers. Automatic recognition of slave addresses is provided in all energy modes.

# 2.1.12 Universal Synchronous/Asynchronous Receiver/Transmitter (US-ART)

The Universal Synchronous Asynchronous serial Receiver and Transmitter (USART) is a very flexible serial I/O module. It supports full duplex asynchronous UART communication as well as RS-485, SPI, MicroWire and 3-wire. It can also interface with ISO7816 SmartCards, IrDA and I2S devices.

## 2.1.13 Pre-Programmed USB/UART Bootloader

The bootloader presented in application note AN0042 is pre-programmed in the device at factory. The bootloader enables users to program the EFM32 through a UART or a USB CDC class virtual UART without the need for a debugger. The autobaud feature, interface and commands are described further in the application note.

# 2.1.14 Low Energy Universal Asynchronous Receiver/Transmitter (LEUART)

The unique LEUART<sup>TM</sup>, the Low Energy UART, is a UART that allows two-way UART communication on a strict power budget. Only a 32.768 kHz clock is needed to allow UART communication up to 9600 baud/s. The LEUART includes all necessary hardware support to make asynchronous serial communication possible with minimum of software intervention and energy consumption.

### 2.1.15 Timer/Counter (TIMER)

The 16-bit general purpose Timer has 3 compare/capture channels for input capture and compare/Pulse-Width Modulation (PWM) output. TIMER0 also includes a Dead-Time Insertion module suitable for motor control applications.

## 2.1.16 Real Time Counter (RTC)

The Real Time Counter (RTC) contains a 24-bit counter and is clocked either by a 32.768 kHz crystal oscillator, or a 32.768 kHz RC oscillator. In addition to energy modes EM0 and EM1, the RTC is also available in EM2. This makes it ideal for keeping track of time since the RTC is enabled in EM2 where most of the device is powered down.

### 2.1.17 Backup Real Time Counter (BURTC)

The Backup Real Time Counter (BURTC) contains a 32-bit counter and is clocked either by a 32.768 kHz crystal oscillator, a 32.768 kHz RC oscillator or a 1 kHz ULFRCO. The BURTC is available in all Energy Modes and it can also run in backup mode, making it operational even if the main power should drain out.

# **3 Electrical Characteristics**

## **3.1 Test Conditions**

#### 3.1.1 Typical Values

The typical data are based on  $T_{AMB}$ =25°C and  $V_{DD}$ =3.0 V, as defined in Table 3.2 (p. 10), unless otherwise specified.

#### 3.1.2 Minimum and Maximum Values

The minimum and maximum values represent the worst conditions of ambient temperature, supply voltage and frequencies, as defined in Table 3.2 (p. 10), unless otherwise specified.

## **3.2 Absolute Maximum Ratings**

The absolute maximum ratings are stress ratings, and functional operation under such conditions are not guaranteed. Stress beyond the limits specified in Table 3.1 (p. 10) may affect the device reliability or cause permanent damage to the device. Functional operating conditions are given in Table 3.2 (p. 10).

#### Table 3.1. Absolute Maximum Ratings

Symbol	Parameter	Condition	Min	Тур	Мах	Unit
T <sub>STG</sub>	Storage tempera- ture range		-40		150	°C
Τ <sub>S</sub>	Maximum soldering temperature	Latest IPC/JEDEC J-STD-020 Standard			260	°C
V <sub>DDMAX</sub>	External main sup- ply voltage		0		3.8	V
VIOPIN	Voltage on any I/O pin		-0.3		V <sub>DD</sub> +0.3	V
1	Current per I/O pin (sink)				100	mA
I <sub>IOMAX</sub>	Current per I/O pin (source)				-100	mA

## **3.3 General Operating Conditions**

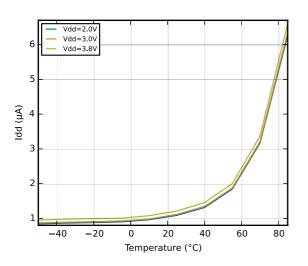
### 3.3.1 General Operating Conditions

#### Table 3.2. General Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
T <sub>AMB</sub>	Ambient temperature range	-40		85	°C
V <sub>DDOP</sub>	Operating supply voltage	1.98		3.8	V
f <sub>APB</sub>	Internal APB clock frequency			48	MHz
f <sub>AHB</sub>	Internal AHB clock frequency			48	MHz

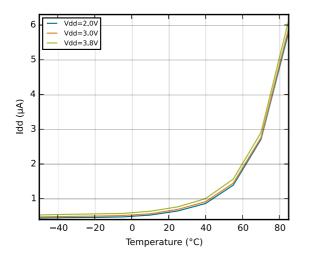
### 3.4.1 EM2 Current Consumption

Figure 3.1. EM2 current consumption. RTC<sup>1</sup> prescaled to 1 Hz, 32.768 kHz LFRCO.



### 3.4.2 EM3 Current Consumption

Figure 3.2. EM3 current consumption.



<sup>&</sup>lt;sup>1</sup>Using backup RTC.

## 3.7 Flash

#### Table 3.6. Flash

Symbol	Parameter	Condition	Min	Тур	Max	Unit
EC <sub>FLASH</sub>	Flash erase cycles before failure		20000			cycles
		T <sub>AMB</sub> <150°C	10000			h
RET <sub>FLASH</sub>	Flash data retention	T <sub>AMB</sub> <85°C	10			years
		T <sub>AMB</sub> <70°C	20			years
t <sub>W_PROG</sub>	Word (32-bit) pro- gramming time		20			μs
	Dago orogo timo	LPERASE == 0	20	20.4	20.8	ms
t <sub>PERASE</sub>	Page erase time	LPERASE == 1	40	40.4	40.8	ms
t <sub>DERASE</sub>	Device erase time				161.6	ms
		LPERASE == 0			14 <sup>1</sup>	mA
I <sub>ERASE</sub>	Erase current	LPERASE == 1			7 <sup>1</sup>	mA
		LPWRITE == 0			14 <sup>1</sup>	mA
I <sub>WRITE</sub>	Write current	LPWRITE == 1			7 <sup>1</sup>	mA
V <sub>FLASH</sub>	Supply voltage dur- ing flash erase and write		1.98		3.8	V

<sup>1</sup>Measured at 25°C

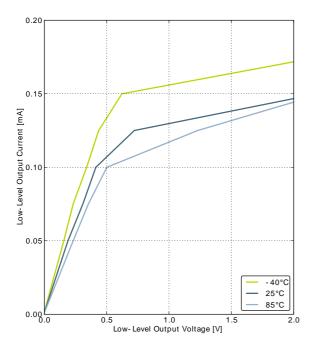
## **3.8 General Purpose Input Output**

#### Table 3.7. GPIO

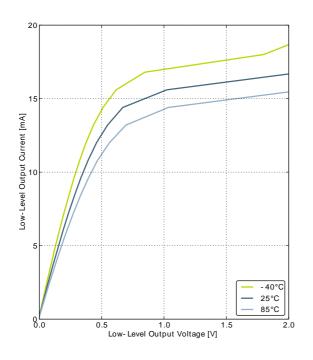
Symbol	Parameter	Condition	Min	Тур	Max	Unit
V <sub>IOIL</sub>	Input low voltage				0.30V <sub>DD</sub>	V
V <sub>IOIH</sub>	Input high voltage		0.70V <sub>DD</sub>			V
		Sourcing 0.1 mA, V <sub>DD</sub> =1.98 V, GPIO_Px_CTRL DRIVEMODE = LOWEST		0.80V <sub>DD</sub>		V
		Sourcing 0.1 mA, V <sub>DD</sub> =3.0 V, GPIO_Px_CTRL DRIVEMODE = LOWEST		0.90V <sub>DD</sub>		V
	Output high volt- age (Production test	Sourcing 1 mA, V <sub>DD</sub> =1.98 V, GPIO_Px_CTRL DRIVEMODE = LOW		0.85V <sub>DD</sub>		V
V <sub>IOOH</sub>	condition = 3.0V, DRIVEMODE = STANDARD)	Sourcing 1 mA, V <sub>DD</sub> =3.0 V, GPIO_Px_CTRL DRIVEMODE = LOW		0.90V <sub>DD</sub>		V
		Sourcing 6 mA, V <sub>DD</sub> =1.98 V, GPIO_Px_CTRL DRIVEMODE = STANDARD	0.75V <sub>DD</sub>			V
		Sourcing 6 mA, V <sub>DD</sub> =3.0 V, GPIO_Px_CTRL DRIVEMODE = STANDARD	0.85V <sub>DD</sub>			V



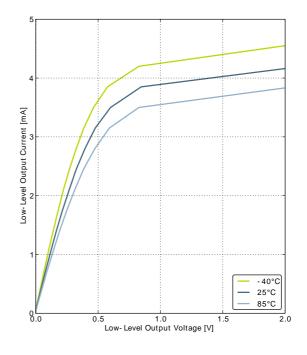
#### Figure 3.4. Typical Low-Level Output Current, 2V Supply Voltage



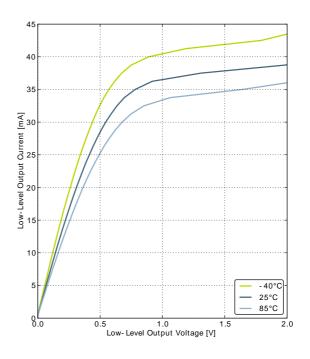
GPIO\_Px\_CTRL DRIVEMODE = LOWEST



GPIO\_Px\_CTRL DRIVEMODE = STANDARD



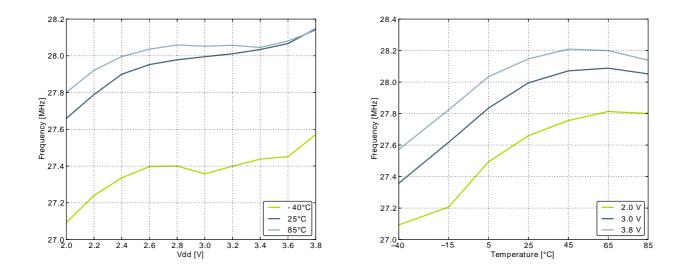
GPIO\_Px\_CTRL DRIVEMODE = LOW



GPIO\_Px\_CTRL DRIVEMODE = HIGH



#### Figure 3.16. Calibrated HFRCO 28 MHz Band Frequency vs Supply Voltage and Temperature



#### 3.9.5 AUXHFRCO

#### Table 3.12. AUXHFRCO

Symbol	Parameter	Condition	Min	Тур	Max	Unit
		28 MHz frequency band	27.5	28.0	28.5	MHz
		21 MHz frequency band	20.6	21.0	21.4	MHz
£	Oscillation frequen-	14 MHz frequency band	13.7	14.0	14.3	MHz
<sup>†</sup> AUXHFRCO	су, V <sub>DD</sub> = 3.0 V, Т <sub>АМВ</sub> =25°С	11 MHz frequency band	10.8	11.0	11.2	MHz
		7 MHz frequency band	6.48 <sup>1</sup>	6.60 <sup>1</sup>	6.72 <sup>1</sup>	MHz
		1 MHz frequency band	1.15 <sup>2</sup>	1.20 <sup>2</sup>	1.25 <sup>2</sup>	MHz
t <sub>AUXHFRCO_settlir</sub>	<sub>g</sub> Settling time after start-up	f <sub>AUXHFRCO</sub> = 14 MHz		0.6		Cycles
DC <sub>AUXHFRCO</sub>	Duty cycle	f <sub>AUXHFRCO</sub> = 14 MHz	48.5	50	51	%
TUNESTEP <sub>AU&gt;</sub> HFRCO	Frequency step for LSB change in TUNING value			0.3 <sup>3</sup>		%

<sup>1</sup>For devices with prod. rev. < 19, Typ = 7MHz and Min/Max values not applicable.

 $^{2}$ For devices with prod. rev. < 19, Typ = 1MHz and Min/Max values not applicable.

<sup>3</sup>The TUNING field in the CMU\_AUXHFRCOCTRL register may be used to adjust the AUXHFRCO frequency. There is enough adjustment range to ensure that the frequency bands above 7 MHz will always have some overlap across supply voltage and temperature. By using a stable frequency reference such as the LFXO or HFXO, a firmware calibration routine can vary the TUNING bits and the frequency band to maintain the AUXHFRCO frequency at any arbitrary value between 7 MHz and 28 MHz across operating conditions.

## 3.9.6 ULFRCO

#### Table 3.13. ULFRCO

Symbol	Parameter	Condition	Min	Тур	Мах	Unit
fulfrco	Oscillation frequen- cy	25°C, 3V	0.70		1.75	kHz
TC <sub>ULFRCO</sub>	Temperature coeffi- cient			0.05		%/°C
VC <sub>ULFRCO</sub>	Supply voltage co- efficient			-18.2		%/V

## **3.10 Analog Digital Converter (ADC)**

#### Table 3.14. ADC

Symbol	Parameter	Condition	Min	Тур	Max	Unit
		Single ended	0		V <sub>REF</sub>	V
V <sub>ADCIN</sub>	Input voltage range	Differential	-V <sub>REF</sub> /2		V <sub>REF</sub> /2	V
V <sub>ADCREFIN</sub>	Input range of exter- nal reference volt- age, single ended and differential		1.25		V <sub>DD</sub>	V
V <sub>ADCREFIN_CH7</sub>	Input range of ex- ternal negative ref- erence voltage on channel 7	See V <sub>ADCREFIN</sub>	0		V <sub>DD</sub> - 1.1	V
V <sub>ADCREFIN_CH6</sub>	Input range of ex- ternal positive ref- erence voltage on channel 6	See V <sub>ADCREFIN</sub>	0.625		V <sub>DD</sub>	V
V <sub>ADCCMIN</sub>	Common mode in- put range		0		V <sub>DD</sub>	V
	Input current	2pF sampling capacitors		<100		nA
CMRR <sub>ADC</sub>	Analog input com- mon mode rejection ratio			65		dB
		1 MSamples/s, 12 bit, external reference		351		μA
		10 kSamples/s 12 bit, internal 1.25 V reference, WARMUP- MODE in ADCn_CTRL set to 0b00		67		μA
I <sub>ADC</sub>	Average active cur- rent	10 kSamples/s 12 bit, internal 1.25 V reference, WARMUP- MODE in ADCn_CTRL set to 0b01		63		μA
		10 kSamples/s 12 bit, internal 1.25 V reference, WARMUP- MODE in ADCn_CTRL set to 0b10		64		μA
I <sub>ADCREF</sub>	Current consump- tion of internal volt- age reference	Internal voltage reference		65		μA

## 3.10.1 Typical performance

#### Figure 3.19. ADC Frequency Spectrum, Vdd = 3V, Temp = 25°C

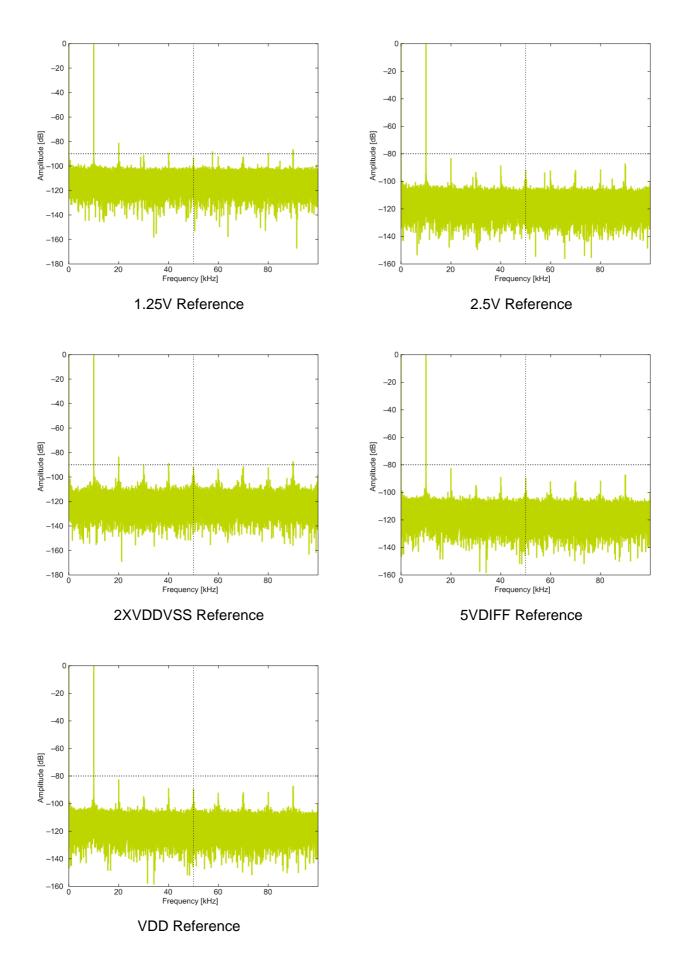




Figure 3.22. ADC Absolute Offset, Common Mode = Vdd /2

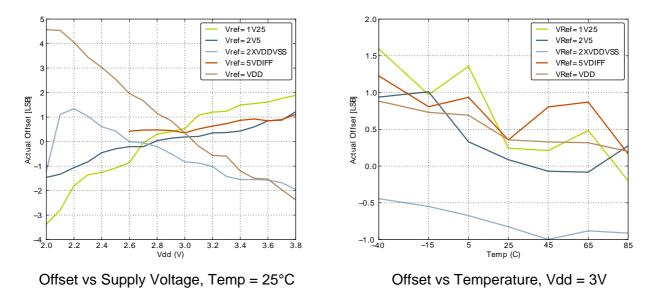
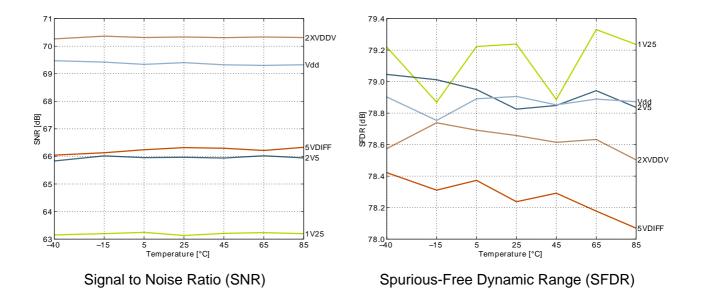


Figure 3.23. ADC Dynamic Performance vs Temperature for all ADC References, Vdd = 3V





Symbol	Parameter	Condition	Min	Тур	Max	Unit
		V <sub>out</sub> =1V, RESSEL=0, 0.1 Hz <f<1 mhz,="" opaxhcmdis="0&lt;/td"><td></td><td>196</td><td></td><td>μV<sub>RMS</sub></td></f<1>		196		μV <sub>RMS</sub>
		V <sub>out</sub> =1V, RESSEL=0, 0.1 Hz <f<1 mhz,="" opaxhcmdis="1&lt;/td"><td></td><td>229</td><td></td><td>μV<sub>RMS</sub></td></f<1>		229		μV <sub>RMS</sub>
		RESSEL=7, 0.1 Hz <f<10 khz,<br="">OPAxHCMDIS=0</f<10>		1230		μV <sub>RMS</sub>
		RESSEL=7, 0.1 Hz <f<10 khz,<br="">OPAxHCMDIS=1</f<10>		2130		μV <sub>RMS</sub>
		RESSEL=7, 0.1 Hz <f<1 mhz,<br="">OPAxHCMDIS=0</f<1>		1630		μV <sub>RMS</sub>
		RESSEL=7, 0.1 Hz <f<1 mhz,<br="">OPAxHCMDIS=1</f<1>		2590		μV <sub>RMS</sub>

Figure 3.25. OPAMP Common Mode Rejection Ratio

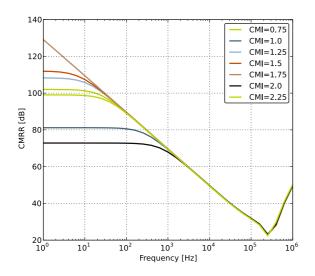
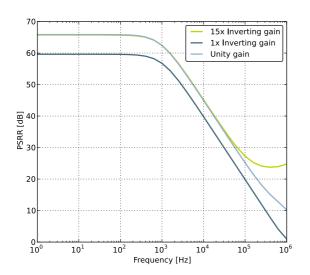


Figure 3.26. OPAMP Positive Power Supply Rejection Ratio





**EFM<sup>®</sup>32** 

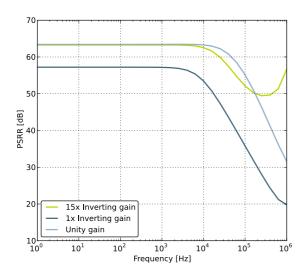


Figure 3.28. OPAMP Voltage Noise Spectral Density (Unity Gain) Vout=1V

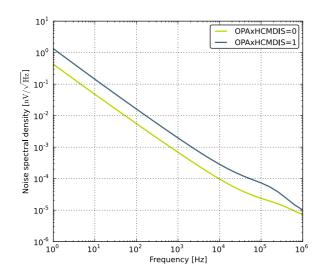
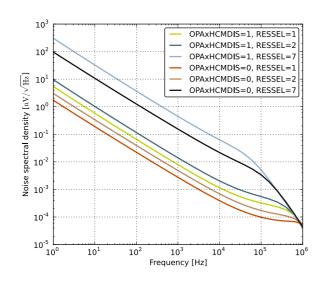


Figure 3.29. OPAMP Voltage Noise Spectral Density (Non-Unity Gain)



# **4 Pinout and Package**

#### Note

Please refer to the application note "AN0002 EFM32 Hardware Design Considerations" for guidelines on designing Printed Circuit Boards (PCB's) for the EFM32GG942.

#### 4.1 Pinout

The *EFM32GG942* pinout is shown in Figure 4.1 (p. 51) and Table 4.1 (p. 51). Alternate locations are denoted by "#" followed by the location number (Multiple locations on the same pin are split with "/"). Alternate locations can be configured in the LOCATION bitfield in the \*\_ROUTE register in the module in question.

#### Figure 4.1. EFM32GG942 Pinout (top view, not to scale)

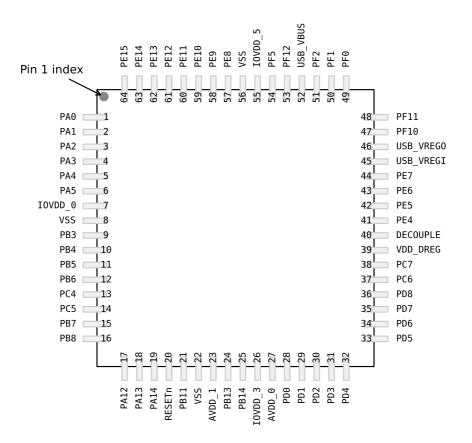


Table 4.1. Device Pinout

	QFP64 Pin# and Name		Pin Alternate Functio	Inctionality / Description		
Pin #	Pin Name	Analog	Timers	Communication	Other	
1	PA0	LCD_SEG13	TIM0_CC0 #0/1/4	I2C0_SDA #0 LEU0_RX #4	PRS_CH0 #0 GPIO_EM4WU0	
2	PA1	LCD_SEG14	TIM0_CC1 #0/1	12C0_SCL #0	CMU_CLK1 #0 PRS_CH1 #0	
3	PA2	LCD_SEG15	TIM0_CC2 #0/1		CMU_CLK0 #0	



	QFP64 Pin# and Name		Pin Alternate Functi	onality / Description	
Pin #	Pin Name	Analog	Timers	Communication	Other
31	PD3	ADC0_CH3 OPAMP_N2	TIM0_CC2 #3	US1_CS #1	ETM_TD1 #0/2
32	PD4	ADC0_CH4 OPAMP_P2		LEU0_TX #0	ETM_TD2 #0/2
33	PD5	ADC0_CH5 OPAMP_OUT2 #0		LEU0_RX #0	ETM_TD3 #0/2
34	PD6	ADC0_CH6 OPAMP_P1	LETIM0_OUT0 #0 TIM1_CC0 #4 PCNT0_S0IN #3	US1_RX #2 I2C0_SDA #1	LES_ALTEX0 #0 ACMP0_O #2 ETM_TD0 #0
35	PD7	ADC0_CH7 OPAMP_N1	LETIM0_OUT1 #0 TIM1_CC1 #4 PCNT0_S1IN #3	US1_TX #2 I2C0_SCL #1	CMU_CLK0 #2 LES_ALTEX1 #0 ACMP1_O #2 ETM_TCLK #0
36	PD8	BU_VIN			CMU_CLK1 #1
37	PC6	ACMP0_CH6		I2C0_SDA #2 LEU1_TX #0	LES_CH6 #0 ETM_TCLK #2
38	PC7	ACMP0_CH7		I2C0_SCL #2 LEU1_RX #0	LES_CH7 #0 ETM_TD0 #2
39	VDD_DREG	Power supply for on-chip voltage	ge regulator.	1	I
40	DECOUPLE	Decouple output for on-chip vo	Itage regulator. An external cap	acitance of size C <sub>DECOUPLE</sub> is rec	quired at this pin.
41	PE4	LCD_COM0		US0_CS #1	
42	PE5	LCD_COM1		US0_CLK #1	
43	PE6	LCD_COM2		US0_RX #1	
44	PE7	LCD_COM3		US0_TX #1	
45	USB_VREGI				
46	USB_VREGO				
47	PF10			USB_DM	
48	PF11			USB_DP	
49	PF0		TIM0_CC0 #5 LETIM0_OUT0 #2	US1_CLK #2 I2C0_SDA #5 LEU0_TX #3	DBG_SWCLK #0/1/2/3
50	PF1		TIM0_CC1 #5 LETIM0_OUT1 #2	US1_CS #2 I2C0_SCL #5 LEU0_RX #3	DBG_SWDIO #0/1/2/3 GPIO_EM4WU3
51	PF2	LCD_SEG0	TIM0_CC2 #5	LEU0_TX #4	ACMP1_O #0 DBG_SWO #0 GPIO_EM4WU4
52	USB_VBUS	USB 5.0 V VBUS input.	l	1	1
53	PF12			USB_ID	
54	PF5	LCD_SEG3	TIM0_CDTI2 #2/5	USB_VBUSEN #0	PRS_CH2 #1
55	IOVDD_5	Digital IO power supply 5.		1	1
56	VSS	Ground.			
57	PE8	LCD_SEG4	PCNT2_S0IN #1		PRS_CH3 #1
58	PE9	LCD_SEG5	PCNT2_S1IN #1		
59	PE10	LCD_SEG6	TIM1_CC0 #1	US0_TX #0	BOOT_TX
60	PE11	LCD_SEG7	TIM1_CC1 #1	US0_RX #0	LES_ALTEX5 #0 BOOT_RX
61	PE12	LCD_SEG8	TIM1_CC2 #1	US0_RX #3	CMU_CLK1 #2



	QFP64 Pin# and Name						
Pin #	Pin Name	Analog	Timers	Communication	Other		
				US0_CLK #0 I2C0_SDA #6	LES_ALTEX6 #0		
62	PE13	LCD_SEG9		US0_TX #3 US0_CS #0 I2C0_SCL #6	LES_ALTEX7 #0 ACMP0_O #0 GPIO_EM4WU5		
63	PE14	LCD_SEG10	TIM3_CC0 #0	LEU0_TX #2			
64	PE15	LCD_SEG11	TIM3_CC1 #0	LEU0_RX #2			

## **4.2 Alternate Functionality Pinout**

A wide selection of alternate functionality is available for multiplexing to various pins. This is shown in Table 4.2 (p. 54). The table shows the name of the alternate functionality in the first column, followed by columns showing the possible LOCATION bitfield settings.

#### Note

Some functionality, such as analog interfaces, do not have alternate settings or a LOCA-TION bitfield. In these cases, the pinout is shown in the column corresponding to LOCA-TION 0.

#### Table 4.2. Alternate functionality overview

Alternate			LOC	ATION				
Functionality	0	1	2	3	4	5	6	Description
ACMP0_CH4	PC4							Analog comparator ACMP0, channel 4.
ACMP0_CH5	PC5							Analog comparator ACMP0, channel 5.
ACMP0_CH6	PC6							Analog comparator ACMP0, channel 6.
ACMP0_CH7	PC7							Analog comparator ACMP0, channel 7.
ACMP0_O	PE13		PD6					Analog comparator ACMP0, digital output.
ACMP1_O	PF2		PD7					Analog comparator ACMP1, digital output.
ADC0_CH0	PD0							Analog to digital converter ADC0, input channel number 0.
ADC0_CH1	PD1							Analog to digital converter ADC0, input channel number 1.
ADC0_CH2	PD2							Analog to digital converter ADC0, input channel number 2.
ADC0_CH3	PD3							Analog to digital converter ADC0, input channel number 3.
ADC0_CH4	PD4							Analog to digital converter ADC0, input channel number 4.
ADC0_CH5	PD5							Analog to digital converter ADC0, input channel number 5.
ADC0_CH6	PD6							Analog to digital converter ADC0, input channel number 6.
ADC0_CH7	PD7							Analog to digital converter ADC0, input channel number 7.
BOOT_RX	PE11							Bootloader RX.
BOOT_TX	PE10							Bootloader TX.
BU_VIN	PD8							Battery input for Backup Power Domain
CMU_CLK0	PA2		PD7					Clock Management Unit, clock output number 0.
CMU_CLK1	PA1	PD8	PE12					Clock Management Unit, clock output number 1.
OPAMP_N0	PC5							Operational Amplifier 0 external negative input.
OPAMP_N1	PD7							Operational Amplifier 1 external negative input.

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Alternate			LOC	ATION				
Functionality	0	1	2	3	4	5	6	Description
LCD_COM0	PE4							LCD driver common line number 0.
LCD_COM1	PE5							LCD driver common line number 1.
LCD_COM2	PE6							LCD driver common line number 2.
LCD_COM3	PE7							LCD driver common line number 3.
LCD_SEG0	PF2							LCD segment line 0. Segments 0, 1, 2 and 3 are con- trolled by SEGEN0.
LCD_SEG3	PF5							LCD segment line 3. Segments 0, 1, 2 and 3 are con- trolled by SEGEN0.
LCD_SEG4	PE8							LCD segment line 4. Segments 4, 5, 6 and 7 are con- trolled by SEGEN1.
LCD_SEG5	PE9							LCD segment line 5. Segments 4, 5, 6 and 7 are con- trolled by SEGEN1.
LCD_SEG6	PE10							LCD segment line 6. Segments 4, 5, 6 and 7 are controlled by SEGEN1.
LCD_SEG7	PE11							LCD segment line 7. Segments 4, 5, 6 and 7 are con- trolled by SEGEN1.
LCD_SEG8	PE12							LCD segment line 8. Segments 8, 9, 10 and 11 are con- trolled by SEGEN2.
LCD_SEG9	PE13							LCD segment line 9. Segments 8, 9, 10 and 11 are con- trolled by SEGEN2.
LCD_SEG10	PE14							LCD segment line 10. Segments 8, 9, 10 and 11 are con- trolled by SEGEN2.
LCD_SEG11	PE15							LCD segment line 11. Segments 8, 9, 10 and 11 are con- trolled by SEGEN2.
LCD_SEG13	PA0							LCD segment line 13. Segments 12, 13, 14 and 15 are controlled by SEGEN3.
LCD_SEG14	PA1							LCD segment line 14. Segments 12, 13, 14 and 15 are controlled by SEGEN3.
LCD_SEG15	PA2							LCD segment line 15. Segments 12, 13, 14 and 15 are controlled by SEGEN3.
LCD_SEG16	PA3							LCD segment line 16. Segments 16, 17, 18 and 19 are controlled by SEGEN4.
LCD_SEG17	PA4							LCD segment line 17. Segments 16, 17, 18 and 19 are controlled by SEGEN4.
LCD_SEG18	PA5							LCD segment line 18. Segments 16, 17, 18 and 19 are controlled by SEGEN4.
LCD_SEG20/ LCD_COM4	PB3							LCD segment line 20. Segments 20, 21, 22 and 23 are controlled by SEGEN5. This pin may also be used as LCD COM line 4
LCD_SEG21/ LCD_COM5	PB4							LCD segment line 21. Segments 20, 21, 22 and 23 are controlled by SEGEN5. This pin may also be used as LCD COM line 5
LCD_SEG22/ LCD_COM6	PB5							LCD segment line 22. Segments 20, 21, 22 and 23 are controlled by SEGEN5. This pin may also be used as LCD COM line 6
LCD_SEG23/ LCD_COM7	PB6							LCD segment line 23. Segments 20, 21, 22 and 23 are controlled by SEGEN5. This pin may also be used as LCD COM line 7
LES_ALTEX0	PD6							LESENSE alternate exite output 0.
LES_ALTEX1	PD7							LESENSE alternate exite output 1.
LES_ALTEX2	PA3							LESENSE alternate exite output 2.
LES_ALTEX3	PA4							LESENSE alternate exite output 3.
LES_ALTEX4	PA5							LESENSE alternate exite output 4.

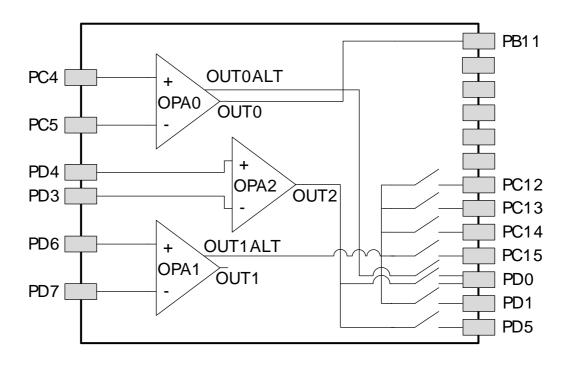
#### Table 4.3. GPIO Pinout

Port	Pin 15	Pin 14	Pin 13	Pin 12	Pin 11	Pin 10	Pin 9	Pin 8	Pin 7	Pin 6	Pin 5	Pin 4	Pin 3	Pin 2	Pin 1	Pin 0
Port A	-	PA14	PA13	PA12	-	-	-	-	-	-	PA5	PA4	PA3	PA2	PA1	PA0
Port B	-	PB14	PB13	-	PB11	-	-	PB8	PB7	PB6	PB5	PB4	PB3	-	-	-
Port C	-	-	-	-	-	-	-	-	PC7	PC6	PC5	PC4	-	-	-	-
Port D	-	-	-	-	-	-	-	PD8	PD7	PD6	PD5	PD4	PD3	PD2	PD1	PD0
Port E	PE15	PE14	PE13	PE12	PE11	PE10	PE9	PE8	PE7	PE6	PE5	PE4	-	-	-	-
Port F	-	-	-	PF12	PF11	PF10	-	-	-	-	PF5	-	-	PF2	PF1	PF0

## 4.4 Opamp Pinout Overview

The specific opamp terminals available in EFM32GG942 is shown in Figure 4.2 (p. 59).

#### Figure 4.2. Opamp Pinout



# **7 Revision History**

## 7.1 Revision 1.40

March 21st, 2016

Added clarification on conditions for INL<sub>ADC</sub> and DNL<sub>ADC</sub> parameters.

Reduced maximum and typical current consumption for all EM0 entries except 48 MHz in the Current Consumption table in the Electrical Characteristics section.

Increased maximum specifications for EM2 current, EM3 current, and EM4 current in the Current Consumption table in the Electrical Characteristics section.

Increased typical specification for EM2 and EM3 current at 85 C in the Current Consumption table in the Electrical Characteristics section.

Added EM2, EM3, and EM4 current consumption vs. temperature graphs.

Added a new EM2 entry and specified the existing specification is for EM0 for the BOD threshold on falling external supply voltage in the Power Management table in the Electrical Characteristics section.

Reduced maximum input leakage current in the GPIO table in the Electrical Characteristics section.

Added a maximum current consumption specification to the LFRCO table in the Electrical Characteristics section.

Added maximum specifications for the active current including references for two channels to the DAC table in the Electrical Characteristics section.

Increased the maximum specification for DAC offset voltage in the DAC table in the Electrical Characteristics section.

Increased the typical specifications for active current with FULLBIAS=1 and capacitive sense internal resistance in the ACMP table in the Electrical Characteristics section.

Added minimum and maximum specifications and updated the typical value for the VCMP offset voltage in the VCMP table in the Electrical Characteristics section.

Removed the maximum specification and reduced the typical value for hysteresis in the VCMP table in the Electrical Characteristics section.

Updated all graphs in the Electrical Characteristics section to display data for 2.0 V as the minimum voltage.

## 7.2 Revision 1.30

May 23rd, 2014

Removed "preliminary" markings

Updated HFRCO figures.

Corrected single power supply voltage minimum value from 1.85V to 1.98V.

Updated Current Consumption information.

Updated Power Management information.

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Updated GPIO information.

Updated LFRCO information.

Updated HFRCO information.

Updated ULFRCO information.

Updated ADC information.

Updated DAC information.

Updated OPAMP information.

Updated ACMP information.

Updated VCMP information.

Added AUXHFRCO information.

## 7.3 Revision 1.21

November 21st, 2013 Updated figures. Updated errata-link. Updated chip marking.

Added link to Environmental and Quality information.

Re-added missing DAC-data.

## 7.4 Revision 1.20

September 30th, 2013

Added I2C characterization data.

Added SPI characterization data.

Corrected the DAC and OPAMP2 pin sharing information in the Alternate Functionality Pinout section.

Corrected GPIO operating voltage from 1.8 V to 1.85 V.

Added the USB bootloader information.

Updated that the EM2 current consumption test was carried out with only one RAM block enabled.

Corrected the ADC resolution from 12, 10 and 6 bit to 12, 8 and 6 bit.

Updated Environmental information.

Updated trademark, disclaimer and contact information.

Other minor corrections.

## 7.5 Revision 1.10

June 28th, 2013

# **B** Contact Information

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Please visit the Silicon Labs Technical Support web page: http://www.silabs.com/support/pages/contacttechnicalsupport.aspx and register to submit a technical support request.